

SN74LVC1G17 Single Schmitt-Trigger Buffer

1 Features

- Available in Ultra Small 0.64-mm² Package (DPW) With 0.5-mm Pitch
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.6 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- MP3 Player/Recorder
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- · Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse

3 Description

This single Schmitt-trigger buffer is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G17 device contains one buffer and performs the Boolean function Y = A.

The CMOS device has high output drive while maintaining low static power dissipation over a broad Vcc operating range.

The SN74LVC1G17 is available in a variety of packages, including the ultra-small DPW package with a body size of 0.8 mm × 0.8mm.

Device Information

DEVICE NAME	PACKAGE ⁽¹⁾	BODY SIZE
	SOT-23 (5)	2.9mm × 1.6mm
	SC70 (5)	2.0mm × 1.25mm
SN74LVC1G17	X2SON (4)	0.8mm × 0.8mm
	SON (6)	1.45mm × 1.0mm
	SON (6)	1.0mm × 1.0mm

For all available packages, see the orderable addendum at the end of the datasheet.



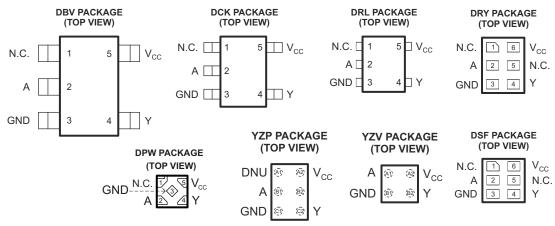


Table of Contents

1 Features	1	8 Detailed Description	10
2 Applications	1	8.1 Overview	10
3 Description		8.2 Functional Block Diagram	
4 Revision History		8.3 Feature Description	
5 Pin Configuration and Functions		8.4 Device Functional Modes	
6 Specifications		9 Applications and Implementation	
6.1 Absolute Maximum Ratings		9.1 Application Information	
6.2 Handling Ratings		9.2 Typical Application	
6.3 Recommended Operating Conditions		10 Power Supply Recommendations	
6.4 Thermal Information		11 Layout	
		11.1 Layout Guidelines 11.2 Layout Example	
6.6 Switching Characteristics, C _L = 15 pF 6.7 Switching Characteristics AC Limit, –40°C TO	/	12 Device and Documentation Support	
85°C	7	12.1 Trademarks	
6.8 Switching Characteristics AC Limit, –40°C TO		12.2 Electrostatic Discharge Caution	
125°C	7	12.3 Glossary	
6.9 Operating Characteristics		13 Mechanical, Packaging, and Orderable	
6.10 Typical Characteristics		Information	14
7 Parameter Measurement Information	8		
Changes from Revision V (April 2014) to Revision		· · ·	Page
 Updated the numbering format for tables, figure 	s, and	cross-references throughout the document	1
 Corrected part number from SN74LVC1G14 to \$ 	SN74L	VC1G17 in the Application Informationsection	11
 Corrected typical application schematic in Typic 	al App	olication section	11
Changes from Revision U (February 2014) to Re	evisio	n V (April 2014)	Page
Added Pin Functions table			3
Added Handling Ratings table			4
Added Thermal Information table			
Added Typical Characteristics.			
, tauda , ippiidation and impionioniation doction.			
 Added Power Supply Recommendations section 			
Added Layout section.			13
Changes from Revision T (November 2012) to F	Revisio	on U (February 2014)	Page
Added Applications			1
 Moved T_{sta} to Handling Ratings table 			4
 Changed MAX operating free-air temperature fr 			
 Added –40°C to 125°C to Electrical Characteris 			
 Added Switching Characteristics table for –40°C 			
Changes from Revision S (June 2011) to Revision		· ·	Page



5 Pin Configuration and Functions



N.C. – No internal connection See mechanical drawings for dimensions. DNU – Do not use

Pin Functions

					in r anotiono				
		PIN							
NAME	DBV, DCK, DRL, DPW	DRY, DSF	YZP	YZV	DESCRIPTION				
NC	1	1, 5	A1, B2	-	Not connected				
Α	2	2	B1	A1	Input				
GND	3	3	C1	B1	Ground				
Y	4	4	C2	B2	Output				
V _{CC}	5	6	A2	A2	Power terminal				



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽¹⁾	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current		±50	mA	
	Continuous current through V _{CC} or GND			±100	mA

- (1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (2) The value of V_{CC} is provided in the Recommended Operating Conditions table.

6.2 Handling Ratings

		MIN	MAX	UNIT
T _{stg}	Storage temperature range	-65	150	°C
v (1)	Human-Body Model (HBM) ⁽²⁾	0	2	kV
V _{ESD} ⁽¹⁾	Charged-Device Model (CDM) ⁽³⁾	0	1	kV

- (1) Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges in to the device.
- (2) Level listed above is the passing level per ANSI, ESDA, and JEDEC JS-001. JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (3) Level listed above is the passing level per EIA-JEDEC JESD22-C101. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Product Folder Links: SN74LVC1G17

6.3 Recommended Operating Conditions

			MIN	MAX	UNIT
	Committee and	Operating	1.65	5.5	
V_{CC}	Supply voltage	Data retention only	1.5		V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 1.65 V		-4	
		V _{CC} = 2.3 V		-8	
I_{OH}	High-level output current	V 0 V		-16	mA
		V _{CC} = 3 V		-24	
		V _{CC} = 4.5 V		-32	
		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I_{OL}	Low-level output current	V 0V		16	mA
		V _{CC} = 3 V		24	
		V _{CC} = 4.5 V		32	
T _A	Operating free-air temperature	'	-40	125	°C

6.4 Thermal Information

				S	N74LVC1G1	7			
	THERMAL METRIC ⁽¹⁾	DBV	DCK	DRL	DRY	YZP	DPW	YZV	UNIT
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	4 PINS	4 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	229	280	350	608	130	340	181	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	164	66	121	432	54	215	1	
$R_{\theta JB}$	Junction-to-board thermal resistance	62	67	171	446	51	294	39	°C/W
ΨЈТ	Junction-to-top characterization parameter	44	2	11	191	1	41	8	- C/VV
ΨЈВ	Junction-to-board characterization parameter	62	66	169	442	50	294	38	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	-	-	198	-	250	-	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics—DC Limit Changes

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPLETIONS			25°C		-40°C	TO 85°C	−40°C 1	TO 125°C	LINUT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	MIN	TYP ⁽¹⁾ MAX	MIN	TYP MAX	UNIT
		1.65 V				0.76	1.13	0.76	1.13	
V _{T+}		2.3 V				1.08	1.56	1.08	1.56	
(Positive-going input threshold		3 V				1.48	1.92	1.48	1.92	V
voltage)		4.5 V				2.19	2.74	2.19	2.74	
		5.5 V				2.65	3.33	2.65	3.33	
		1.65 V				0.35	0.59	0.35	0.59	
V _{T-}		2.3 V				0.56	0.88	0.56	0.88	
(Negative-going input threshold		3 V				0.89	1.2	0.89	1.2	V
voltage)		4.5 V				1.51	1.97	1.51	1.97	
		5.5 V				1.88	2.4	1.88	2.4	
		1.65 V				0.36	0.64	0.36	0.64	
ΔV_T		2.3 V				0.45	0.78	0.45	0.78	
Hysteresis		3 V				0.51	0.83	0.51	0.83	V
$(V_{T+} - V_{T-})$		4.5 V				0.58	0.93	0.58	0.93	
		5.5 V				0.69	1.04	0.69	1.04	
	I _{OH} = -100 μA	1.65 V to 5.5 V				V _{CC} - 0.1		V _{CC} - 0.1		
	I _{OH} = -4 mA	1.65 V				1.2		1.2	,	
V _{OH}	I _{OH} = -8 mA	2.3 V				1.9		1.9	,	V
- G.:	I _{OH} = -16 mA	2.1/				2.4		2.4		
	I _{OH} = -24 mA	3 V				2.3		2.3		
	I _{OH} = -32 mA	4.5 V				3.8		3.8		
	Ι _{ΟL} = 100 μΑ	1.65 V to 5.5 V					0.1		0.1	
	I _{OL} = 4 mA	1.65 V					0.45		0.45	
V _{OL}	I _{OL} = 8 mA	2.3 V					0.3		0.3	V
02	I _{OL} = 16 mA	21/					0.4		0.4	
	I _{OL} = 24 mA	3 V					0.55		0.55	
	I _{OL} = 32 mA	4.5 V					0.55		0.55	
I _I A input	V _I = 5.5 V or GND	0 to 5.5 V					±5		±5	μA
I _{off}	V _I or V _O = 5.5 V	0		-			±10		±10	μA
	V _I = 5.5 V or GND,	1.65 V to 5.5 V					10		10	
Icc	$V_1 = 3.6 \text{ V or GND},$ $I_0 = 0$	3 V to 3.6 V		0.5	1.5					μA
ΔI _{CC}	One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at $V_{C\ C}$ or GND	3 V to 5.5 V		,			500		500	μA
C _I	V _I = V _{CC} or GND	3.3 V		4.5						pF

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

6.6 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 7-1)

						-40°C T	O 85°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = 1 ± 0.2		V _{CC} = 3 ± 0.3		V _{CC} = ± 0.		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	2.8	9.9	1.6	5.5	1.5	4.6	0.9	4.4	ns

6.7 Switching Characteristics AC Limit, -40°C TO 85°C

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 7-2)

			-40°C TO 85°C								
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V				V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Y	3.8	11	2	6.5	1.8	5.5	1.2	5	ns

6.8 Switching Characteristics AC Limit, -40°C TO 125°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 7-2)

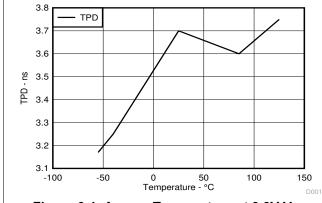
					-	-40°C T	O 125°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	3.8	13	2	8	1.8	6.5	1.2	6	ns

6.9 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	V _{CC} = 5 V	UNIT
	PANAMETER	CONDITIONS	TYP	TYP	TYP	TYP	ONIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	20	21	22	26	pF

6.10 Typical Characteristics



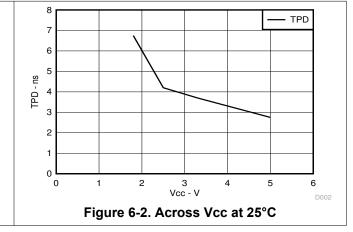
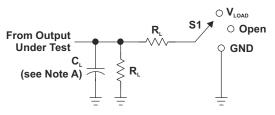


Figure 6-1. Across Temperature at 3.3V Vcc



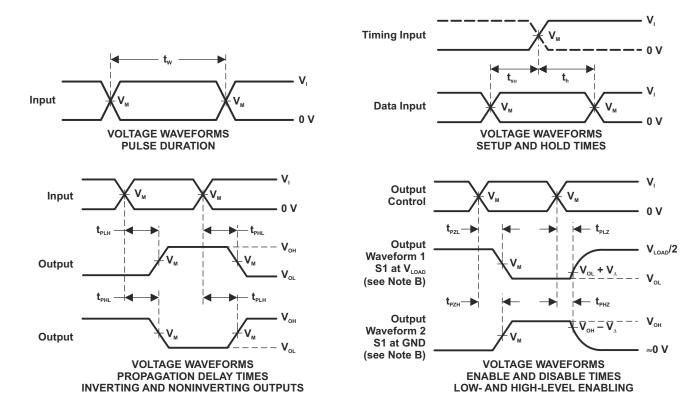
7 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
$t_{_{\mathrm{PLZ}}}/t_{_{\mathrm{PZL}}}$	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

				ΙT

.,	INI	PUTS	.,	.,			.,
V _{cc}	V,	t,/t,	V _M	V _{LOAD}	C _L	R _⊾	V _A
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 M Ω	0.15 V
$2.5~V~\pm~0.2~V$	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 M Ω	0.15 V
$3.3~V\pm0.3~V$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 M Ω	0.3 V
5 V ± 0.5 V	V _{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 M Ω	0.3 V

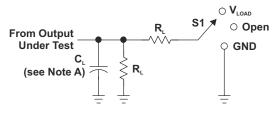


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. $t_{\mbox{\tiny PZL}}$ and $t_{\mbox{\tiny PZH}}$ are the same as $t_{\mbox{\tiny en}}.$
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}.$
- H. All parameters and waveforms are not applicable to all devices.

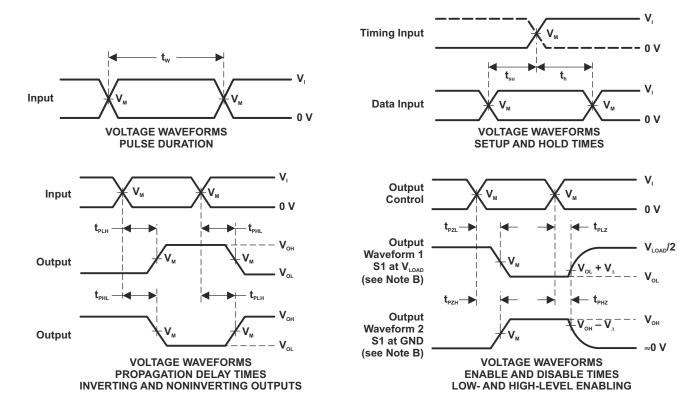
Figure 7-1. Load Circuit and Voltage Waveforms



TEST	S1
t _{PLH} /t _{PHL}	Open
$t_{_{\mathrm{PLZ}}}/t_{_{\mathrm{PZL}}}$	V _{LOAD}
t_{PHZ}/t_{PZH}	GND

LOAD CIRCUIT

V	INF	PUTS	V	V		1	
V _{cc}	V,	t,/t,	V _M	V _{LOAD}	C _L	$R_{\scriptscriptstyle L}$	V _A
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	30 pF	1 k Ω	0.15 V
$2.5~V~\pm~0.2~V$	V_{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	30 pF	500 Ω	0.15 V
$3.3~V\pm0.3~V$	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V_{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_o = 50 \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 7-2. Load Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

The SN74LVC1G17 device contains one Schmitt trigger buffer and performs the Boolean function Y = A. The device functions as an independent buffer, but because of Schmitt action, it will have different input threshold levels for a positive-going (VT+) and negative-going signals.

The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram



8.3 Feature Description

- · Wide operating voltage range.
 - Operates From 1.65 V to 5.5 V.
- · Allows Down voltage translation.
- Inputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

8.4 Device Functional Modes

Table 8-1. Function Table

INPUT A	OUTPUT Y
Н	Н
L	L

9 Applications and Implementation

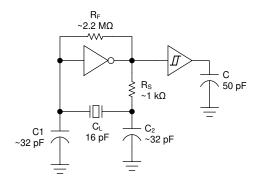
Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74LVC1G17 is a high drive CMOS device that can be used for a multitude of buffer type functions where the input is slow or noisy. It can produce 24 mA of drive current at 3.3 V making it Ideal for driving multiple outputs and good for high speed applications up to 100 MHz. The inputs are 5.5 V tolerant allowing it to translate down to V_{CC} .

9.2 Typical Application



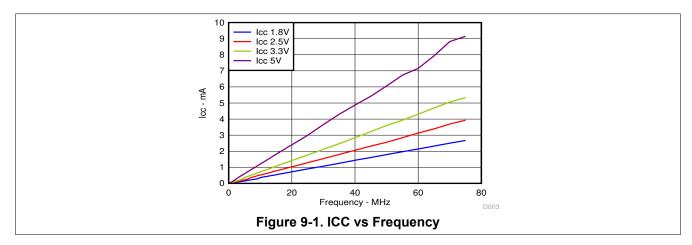
9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs. See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the Recommended Operating
 Conditions table at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed (I_O max) per output and should not exceed (continuous current through V_{CC} or GND) total current for the part. These limits are located in the Absolute Max Ratings table.
 - Outputs should not be pulled above V_{CC}.

9.2.3 Application Curves



10 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

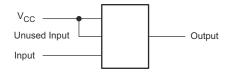
Each Vcc pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply a $0.1-\mu F$ capacitor is recommended and if there are multiple Vcc pins then a $0.01-\mu F$ or $0.022-\mu F$ capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. $0.1-\mu F$ and $1-\mu F$ capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

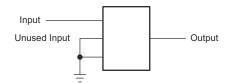
11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input terminals should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to Gnd or Vcc whichever make more sense or is more convenient.

11.2 Layout Example







12 Device and Documentation Support

12.1 Trademarks

All other trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.3 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC1G17





www.ti.com 8-Jun-2022

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G17DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C175, C17F, C17J, C17K, C17R) (C17H, C17P, C17S)	Samples
SN74LVC1G17DBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C17F	Samples
SN74LVC1G17DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C17F	Samples
SN74LVC1G17DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C175, C17F, C17J, C17K, C17R) (C17H, C17P, C17S)	Samples
SN74LVC1G17DBVTE4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C17F	Samples
SN74LVC1G17DBVTG4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C17F	Samples
SN74LVC1G17DCK3	ACTIVE	SC70	DCK	5	3000	RoHS & Non-Green	SNBI	Level-1-260C-UNLIM	-40 to 85	(C7F, C7Z)	Samples
SN74LVC1G17DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C75, C7F, C7J, C7 K, C7R, C7T) (C7H, C7P, C7S)	Samples
SN74LVC1G17DCKRE4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C75 C7S	Samples
SN74LVC1G17DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C75 C7S	Samples
SN74LVC1G17DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C75, C7F, C7J, C7 K, C7R, C7T) (C7H, C7P, C7S)	Samples
SN74LVC1G17DCKTE4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C75 C7S	Samples
SN74LVC1G17DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C75 C7S	Samples
SN74LVC1G17DPWR	ACTIVE	X2SON	DPW	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	S4	Samples
SN74LVC1G17DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(C77, C7R)	Samples



www.ti.com 8-Jun-2022

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G17DRLRG4	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green		Level-1-260C-UNLIM	-40 to 125	(C77, C7R)	Samples
SN74LVC1G17DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C7	Samples
SN74LVC1G17DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	C7	Samples
SN74LVC1G17YZPR	ACTIVE	DSBGA	YZP	5	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	C7N	Samples
SN74LVC1G17YZVR	ACTIVE	DSBGA	YZV	4	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	C7 (7, N)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

PACKAGE OPTION ADDENDUM

www.ti.com 8-Jun-2022

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC1G17:

Automotive: SN74LVC1G17-Q1

● Enhanced Product: SN74LVC1G17-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



www.ti.com 8-Jun-2022

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LVC1G17DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G17DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G17DBVT	SOT-23	DBV	5	250	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LVC1G17DBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74LVC1G17DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G17DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G17DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G17DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74LVC1G17DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G17DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G17DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74LVC1G17DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G17DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

www.ti.com 8-Jun-2022

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G17DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G17DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74LVC1G17DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G17DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G17DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G17YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1
SN74LVC1G17YZVR	DSBGA	YZV	4	3000	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1



www.ti.com 8-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G17DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G17DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G17DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74LVC1G17DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G17DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G17DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G17DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G17DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G17DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74LVC1G17DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G17DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G17DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74LVC1G17DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G17DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G17DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G17DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0



PACKAGE MATERIALS INFORMATION

www.ti.com 8-Jun-2022

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G17DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G17DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G17DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G17YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0
SN74LVC1G17YZVR	DSBGA	YZV	4	3000	220.0	220.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D





PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



YEA (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

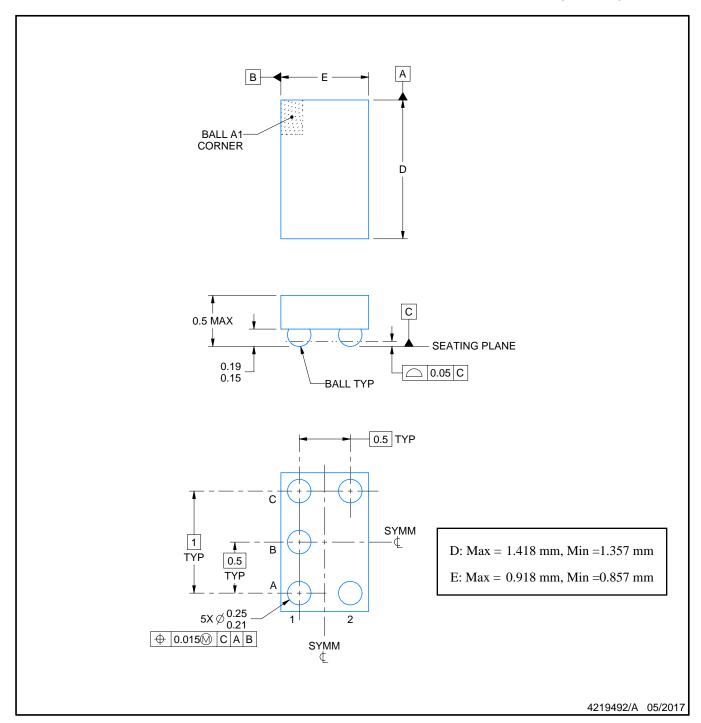
- B. This drawing is subject to change without notice.
- C. NanoStar \mathbf{M} package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is tin-lead (SnPb). Refer to the 5 YZA package (drawing 4204151) for lead-free.

NanoStar is a trademark of Texas Instruments.





DIE SIZE BALL GRID ARRAY



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.





PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-293 Variation UAAD-1



PLASTIC SMALL OUTLINE

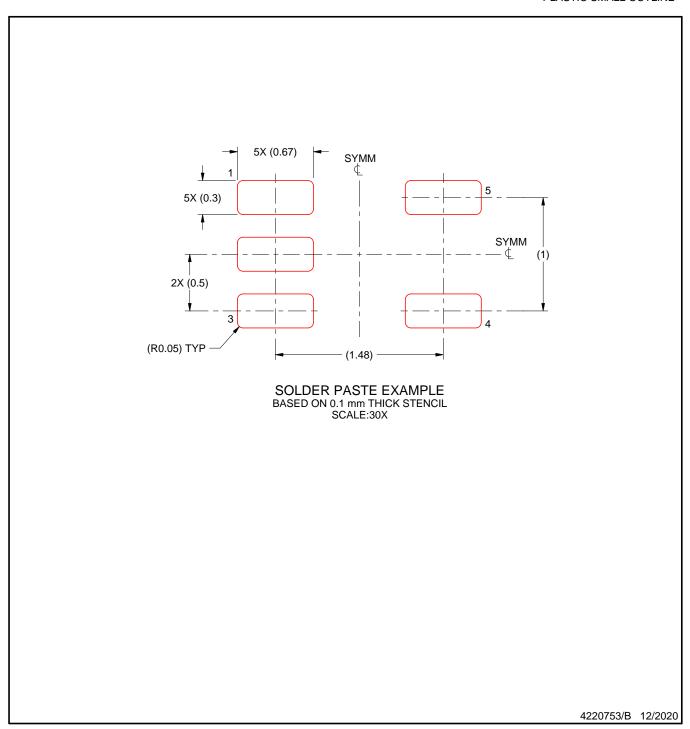


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.

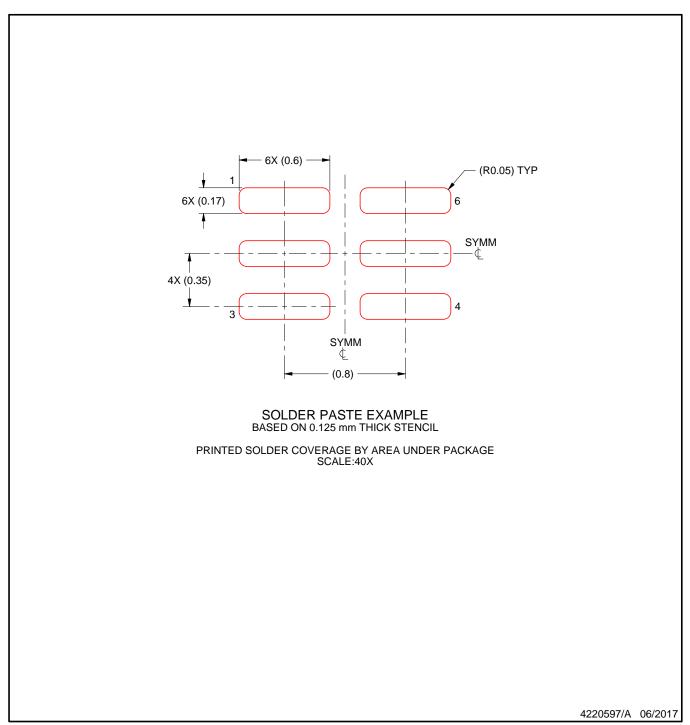




NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



YEP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar \mathbf{M} package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

NanoStar is a trademark of Texas Instruments.



YZA (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is lead-free. Refer to the 5 YEA package (drawing 4203167) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4207181/G



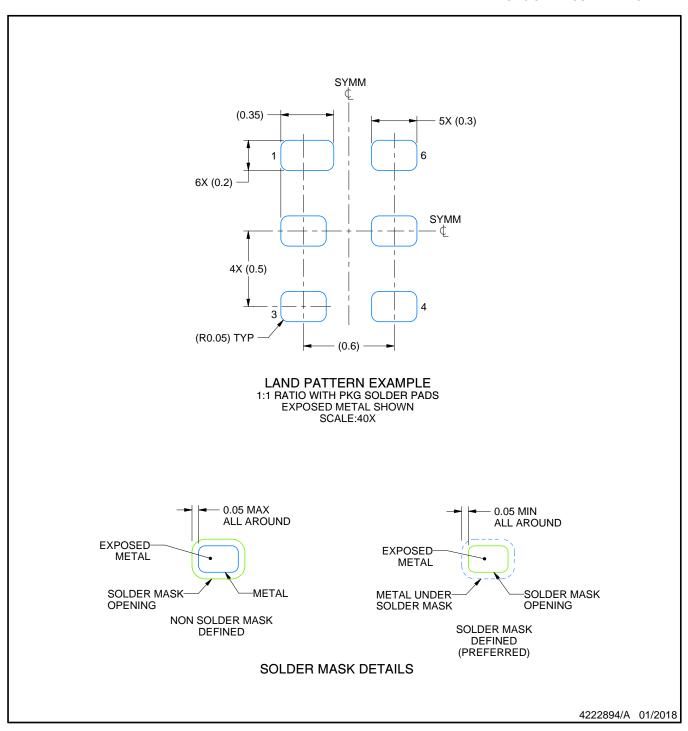




- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.





NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).





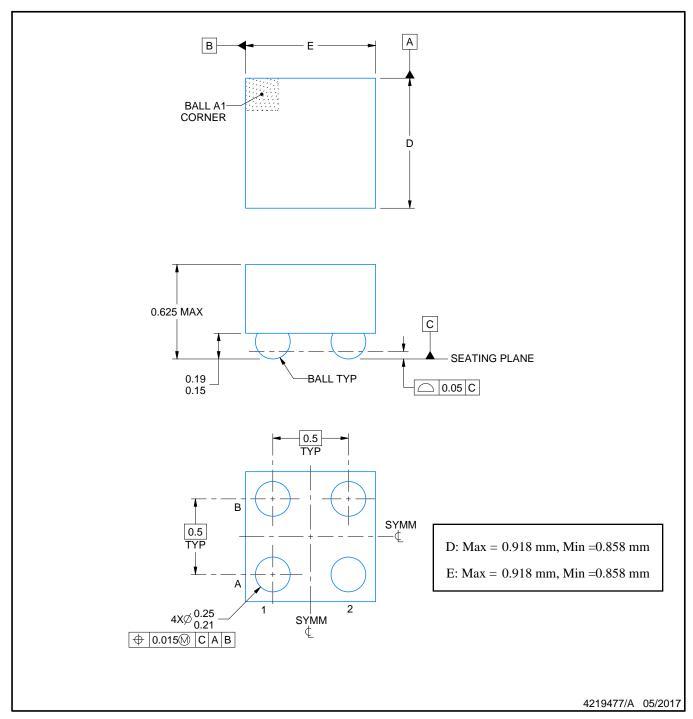
NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY

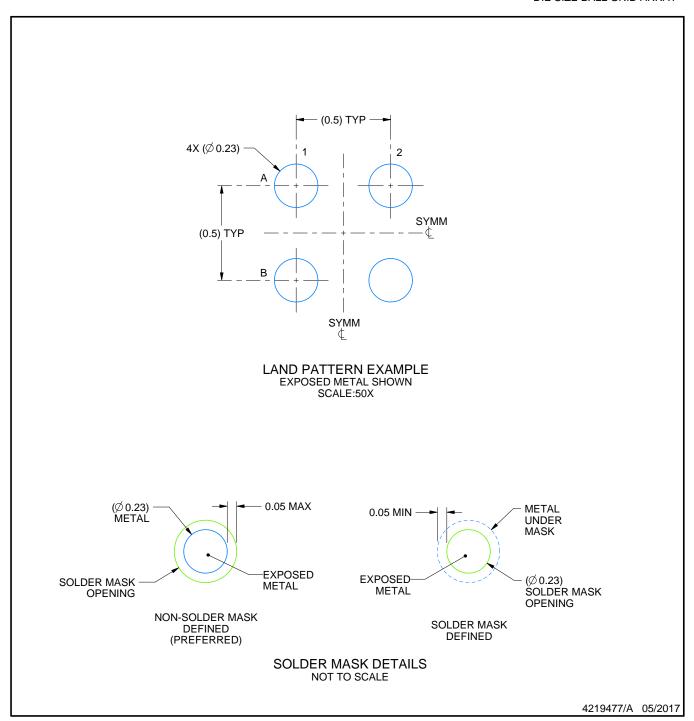


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

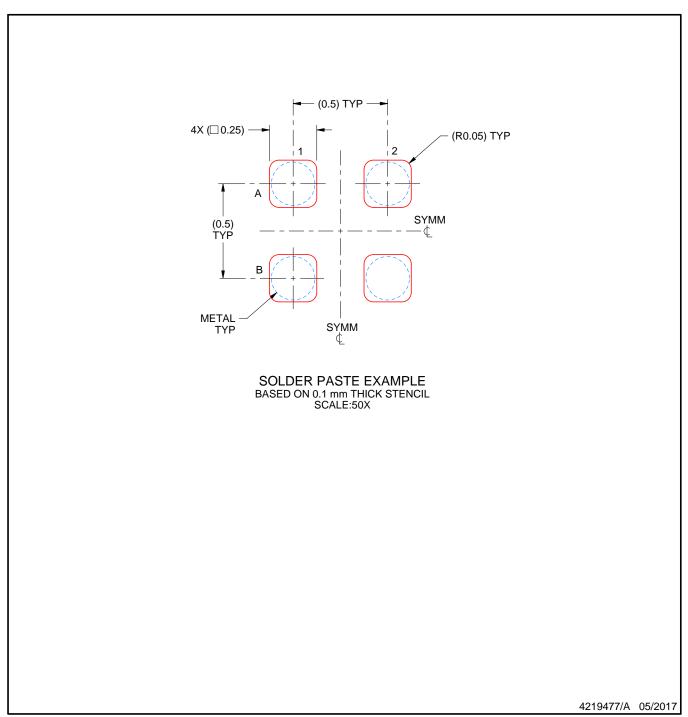


NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. Refer to Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated